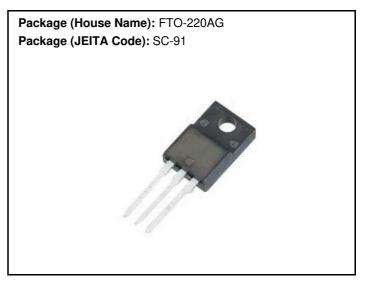
P82F7R5SN

Power MOSFETs 75V, 82A, N-channel

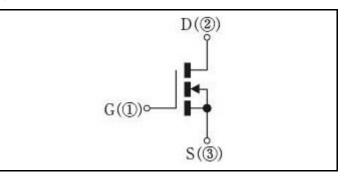
Feature

- N-channel
- Isolated Package
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg		-55 to 150	°C
Channel tempertature	Tch		-55 to 150	°C
Drain-source voltage	V _{DSS}		75	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		82	Α
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	328	Α
Total power dissipation	P _T		58	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	67	Α
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	224	mJ
Dielectric strenght	Vdis	Terminals to case, AC1min	2	kV
Mounting torque	TOR	(Recommended torque: 0.3N·m)	0.5	N∙m

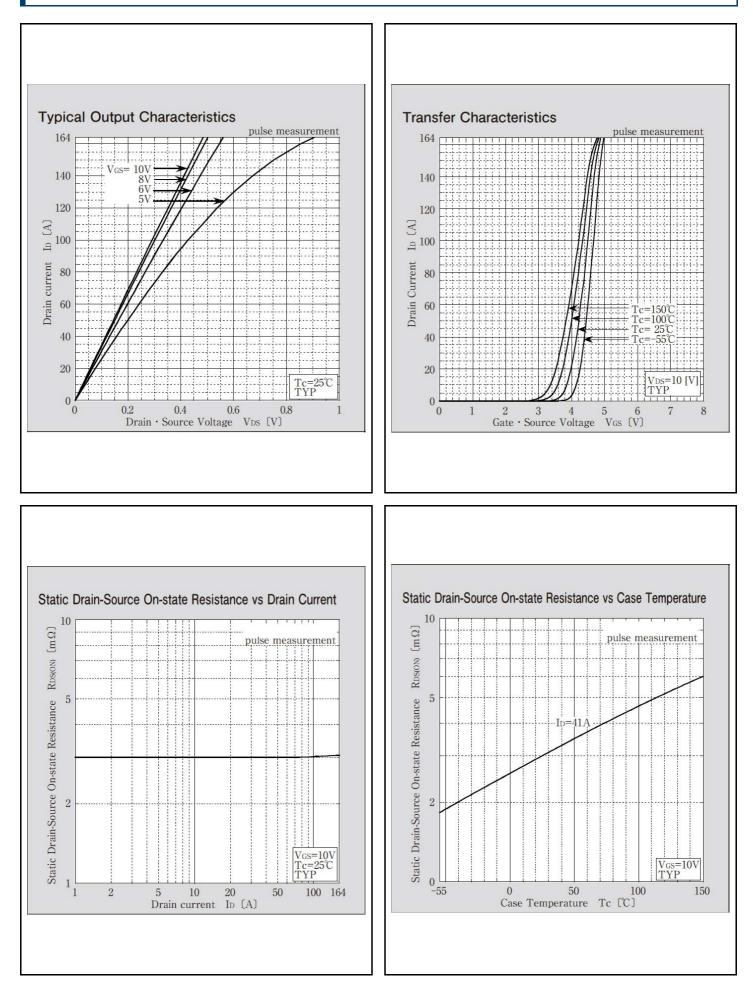
* : See the original Specifications

Electrical Characteristics (unless otherwise specified : Tc=25°C)

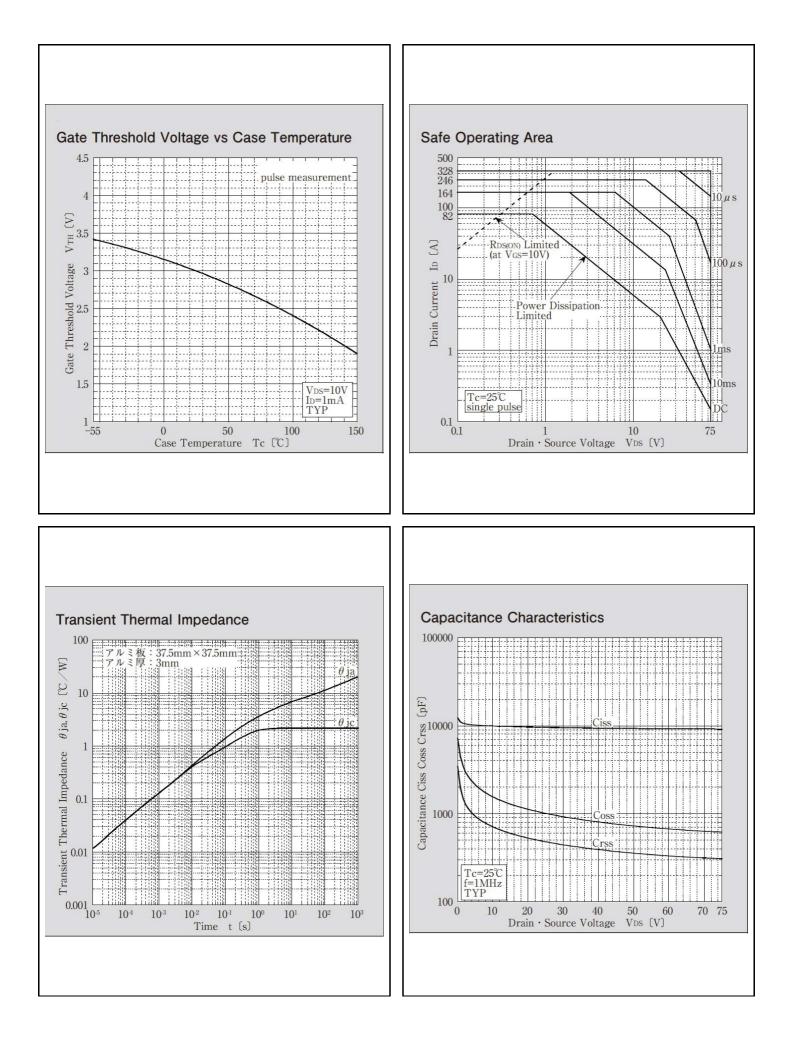
Item	Symbol	Conditions		Ratings		
			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	75			V
Zero gate voltage drain current	I _{DSS}	VDS=75V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g _{fs}	ID=41A, VDS=10V	28			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=41A, VGS=10V		0.003	0.0038	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V _{SD}	IS=82A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink			2.15	°C/W
Total gate charge	Qg	VDD=60V, VGS=10V, ID=82A		168		nC
Gate to source charge	Qgs	VDD=60V, VGS=10V, ID=82A		42		nC
Gate to drain charge	Qgd	VDD=60V, VGS=10V, ID=82A		58		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		9600		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		480		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		1010		pF
Turn-on delay time	td(on)	ID=41A, RL=0.91Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		13		ns
Rise time	tr	ID=41A, RL=0.91Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		47		ns
Turn-off delay time	td(off)	ID=41A, RL=0.91Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		119		ns
Fall time	tf	ID=41A, RL=0.91Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		78		ns
Diode reverse recovery time	trr	IF=82A, VGS=0V, di/dt=100A/µs		58		ns
Diode reverse recovery charge	Qrr	IF=82A, VGS=0V, di/dt=100A/µs		118		nC

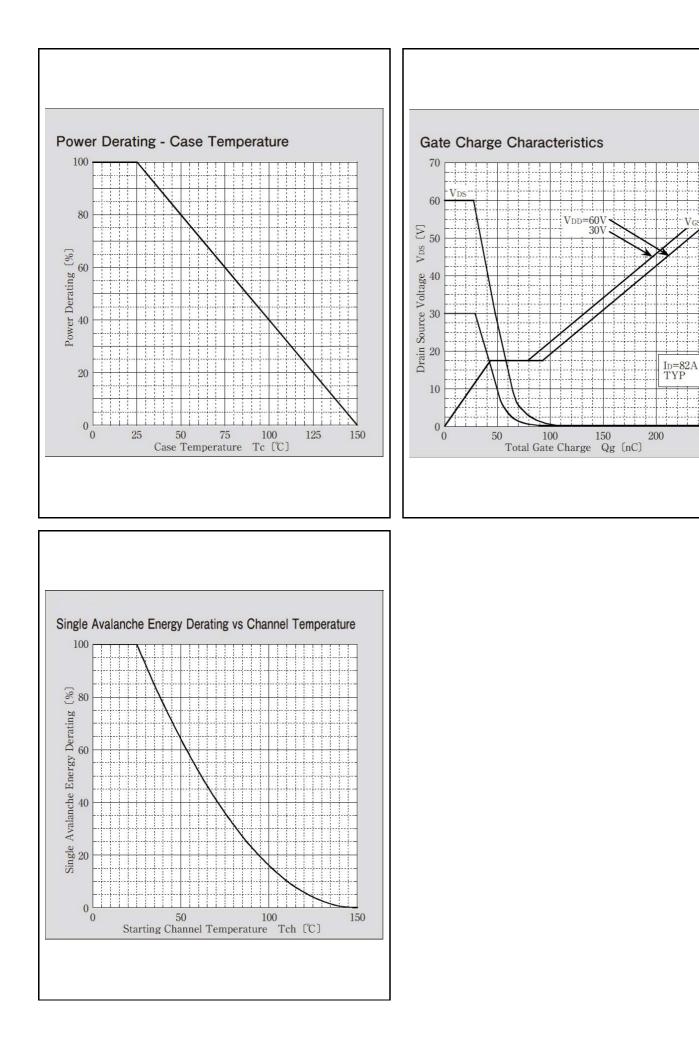
* : See the original Specifications

CHARACTERISTIC DIAGRAMS



3/7





20

15 [<u>N</u>] so <u>N</u>

10

5

250

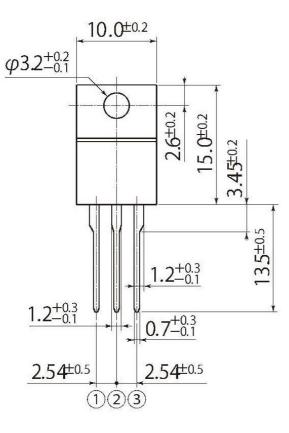
Gate · Source Voltage

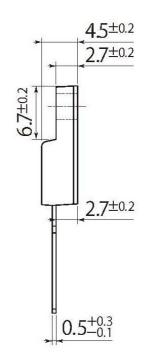
VG

unit:mm

scale: 2/1

J8	JEDEC Code	_		
	JEITA Code	SC-91		
	House Name	FTO-220AG(3pin)		





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[Specific applications]

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